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Quantum percolation in electronic transport of metal–insulator systems: numerical studies of conductance

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Abstract

The quantum site-percolation problem defined by a tight-binding one-electron Hamiltonian on regular simple cubic lattice with binary probability distribution of site energies $P(\varepsilon_{\mathbf{n}}) = p\delta(\varepsilon_{\mathbf{n}}) + (1-p)\delta(\varepsilon_{\mathbf{n}} - \infty)$ is studied using the Landauer–Büttiker formalism and Green's function method. The dimensionless conductance g according to Landauer–Büttiker formula is calculated for a finite system of size $L \times L \times L$. The arithmetic and geometric ($e^{\langle \ln g \rangle}$) averages of g over many realizations of the disordered system are calculated. Plotting g for different L as a function of concentration p has enabled to find a critical $p = p_q$ such that g decreases (exponentially) with L for $p < p_q$ and it increases (linearly) with L when $p > p_q$. Thus, we have demonstrated the Anderson metal–insulator transition at critical concentration p_q from the behaviour of the conductance itself. We have also estimated the critical conductance, g_c as $g_c \equiv g(p_q)$. By estimating the critical point for different values of electron Fermi energy E we have estimated the mobility-edge trajectory and it has been found to be consistent with the corresponding line in the p–E plane obtained by Soukoulis et al. (1987; 1992).

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Keywords: Quantum percolation; Localization; Metal–insulator transition

The estimation of conductance of disordered electron systems has attracted much theoretical interest for more than three decades. Perhaps, most attention has been devoted to the Anderson model [1]. It uses the one-electron tight-binding Hamiltonian on regular lattice with "diagonal" disorder

$$H = \sum_{\mathbf{n}} |\,\mathbf{n} > \varepsilon_{\mathbf{n}} < \mathbf{n}\,| + \sum_{\mathbf{n},\mathbf{m},\mathbf{n}\neq\mathbf{m}} |\,\mathbf{n} > U_{\mathbf{nm}} < \mathbf{m}\,|\,, \tag{1}$$

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